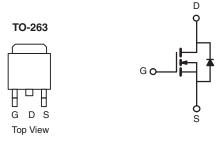


Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	60				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 V$	0.015				
I _D (A)	56				
Configuration	Single				



N-Channel MOSFET

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- · Package with Low Thermal Resistance
- AEC-Q101 Qualified^d
- 100 % $R_{\rm q}$ and UIS Tested
- Characterization Ongoing
- Compliant to RoHS Directive 2002/95/EC





COMPLIANT HALOGEN FREE

ORDERING INFORMATION				
Package	TO-263			
Lead (Pb)-free and Halogen-free	SQM60N06-15-GE3			

ABSOLUTE MAXIMUM RATINGS	Γ _C = 25 °C, unless	s otherwise noted	i)	
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	60	V
Gate-Source Voltage	V _{GS}	± 20	V	
Continuous Drain Current	T _C = 25 °C	I	56	
Continuous Drain Current	T _C = 125 °C	Ι _D	32	
Continuous Source Current (Diode Conduction) ^a		I _S	60	А
Pulsed Drain Current ^b	I _{DM}	227		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	29	
Single Pulse Avalanche Energy		E _{AS}	42	mJ
Meyimum Dewer Dissinction	T _C = 25 °C	D	107	W
Maximum Power Dissipation ^b	T _C = 125 °C	P _D	35	٧V
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to + 175	°C

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	40	°C/W		
Junction-to-Case (Drain)		R _{thJC}	1.4	0/10		

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$		60	-	-	v	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$		-	3.5		
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1.0		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 175 °C	-	-	250		
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	75	-	-	Α	
		V _{GS} = 10 V	I _D = 30 A	-	0.012	0.015		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 V$	I _D = 30 A, T _J = 125 °C	-	-	0.027	Ω	
		V _{GS} = 10 V	I _D = 30 A, T _J = 175 °C	-	-	0.033		
Forward Transconductanceb	9 _{fs}	V _{DS} = 15 V, I _D = 30 A		-	61	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	1983	2480		
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	_{AS} = 0 V V _{DS} = 25 V, f = 1 MHz		314	395	pF	
Reverse Transfer Capacitance	C _{rss}]		-	125	160	1	
Total Gate Charge ^c	Qg			-	33	50		
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = 30 \text{ V}, \text{ I}_{D} = 60 \text{ A}$	-	8.9	-	nC	
Gate-Drain Charge ^c	Q _{gd}	1		-	7.4	-		
Gate Resistance	R _g	f = 1 MHz		0.8	1.6	2.4	Ω	
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = 30 \text{ V}, \text{ R}_{L} = 0.5 \Omega$ $\text{I}_{D} \cong 60 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		-	11	17		
Rise Time ^c	t _r			-	12	18	- ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	21	32		
Fall Time ^c	t _f			-	7	11		
Source-Drain Diode Ratings and Chara	acteristics ^b	·						
Pulsed Current ^a	I _{SM}			-	-	227	А	
Fuised Current ^a	ISM					~~ '	<i>.</i>	

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.

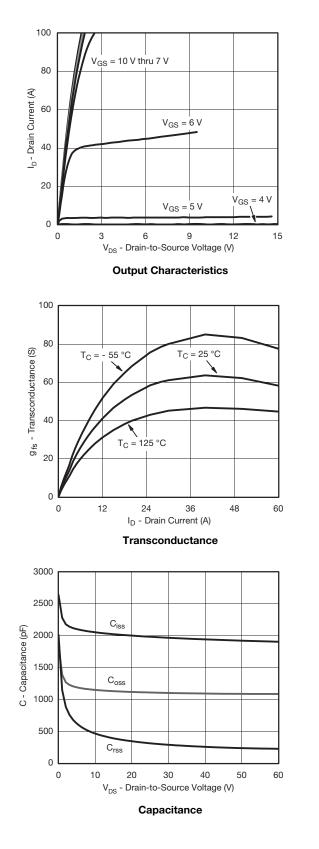
c. Independent of operating temperature.

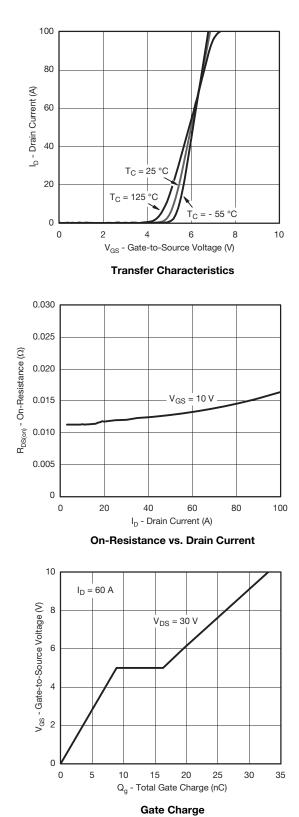
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



Vishay Siliconix

TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)





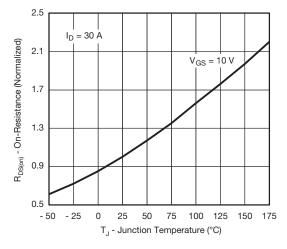
S11-2035-Rev. C, 17-Oct-11

Document Number: 64710

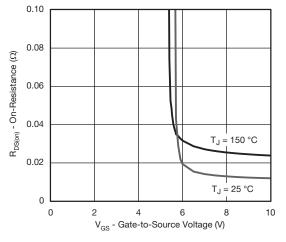


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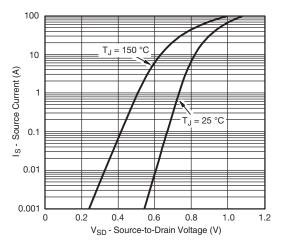
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



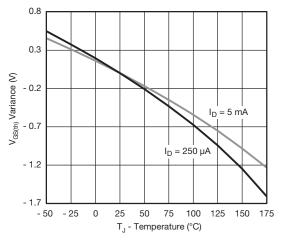




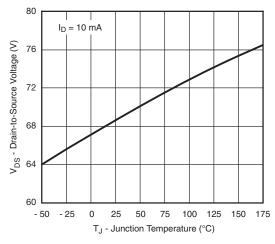
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage







Drain Source Breakdown vs. Junction Temperature

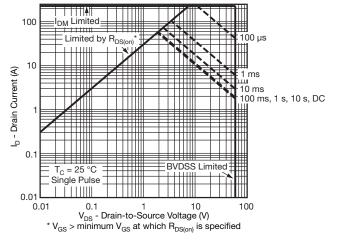
S11-2035-Rev. C, 17-Oct-11

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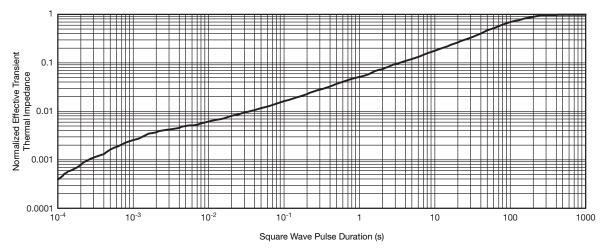


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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Safe Operating Area

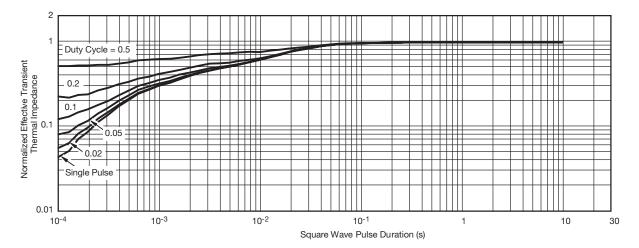


Normalized Thermal Transient Impedance, Junction-to-Ambient



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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

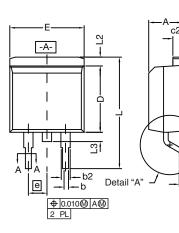
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?64710.

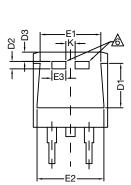


Package Information

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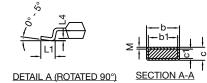
TO-263 (D²PAK): 3-LEAD





-B-

С



		INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
А		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
с*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
	E	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
	E2	0.355 0.375 9.017 9.5		9.525		
	E3	0.072	0.078	1.829	1.981	
е		0.100 BSC		2.54 BSC		
	К	0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
	L4 0.010		BSC	0.254 BSC		
М		-	0.002	-	0.050	
ECN: T10-0738-Rev. J, 03-Jan-11 DWG: 5843						

Notes

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB.
- Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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